

L Number	Hits	Search Text	DB	Time stamp
1	276695	257/\$.ccls. 438./\$.ccls. 365/\$.ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 09:46
2	17760	(257/\$.ccls. 438./\$.ccls. 365/\$.ccls) and (memory with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:29
3	95	((257/\$.ccls. 438./\$.ccls. 365/\$.ccls) and (memory with substrate)) and (((bottom lower top upper) near electrode\$1) with (perovskite (colossal near magnetoresistance (CMR))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:11
4	194	(257/\$.ccls. 438./\$.ccls. 365/\$.ccls) and (((bottom lower top upper) near electrode\$1) with (perovskite (colossal near magnetoresistance (CMR))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:29
5	50084	memory with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:29
6	139	(memory with substrate) and (((bottom lower top upper) near electrode\$1) with (perovskite (colossal near magnetoresistance (CMR))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 10:59
7	4	("5508953"   "5579258"   "6128214"   "6204139").PN.	USPAT	2004/06/21 10:42
8	17	(memory with substrate) and (etch\$3 near2 (open\$3 hole via\$1) near2 ((bottom lower) near electrode\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:20
9	619	(memory with substrate) and ((insulat\$3 isolat\$3) near2 ((bottom lower) near electrode\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31
10	23	((memory with substrate) and ((insulat\$3 isolat\$3) near2 ((bottom lower) near electrode\$1))) and (etch\$3 near2 (open\$3 hole via\$1) near2 (insulat\$ isolat\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31
11	3021	((insulat\$3 isolat\$3) near2 ((bottom lower) near electrode\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31
12	61	(((insulat\$3 isolat\$3) near2 ((bottom lower) near electrode\$1))) and (etch\$3 near2 (open\$3 hole via\$1) near2 (insulat\$ isolat\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/21 11:31